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Sheet	1	of	1
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Application / Conf. No.	10/693,468 / 2533
Filing Date	October 24, 2003
First Named Inventor	Kevin T. Look
Art Unit	2810 2827
Examiner Name	Viet Q. Nguyen
Attorney Docket Number	X-719-ID-2D US

Examiner Initials *	Cite No.¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code (if known)			
W B B B B B B B B B		US- 4,661,833	04-28-87	Mizutani	
		US- 5,650,649	07-22-97	Tsukiji	
		US- 5,708,291	01-13-98	Bohr et al.	
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		US- 5,885,874	03-23-99	Gardner	
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**Examiner
Signature**

V. Novikov

Date
Considered

3/20/05

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Substitute for form 1449A/PTO		Complete if Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application / Conf. No.	Unknown 101 693,468
		Filing Date	October 24, 2003
		First Named Inventor	Kevin T. Look
		Art Unit	Unknown 2827
		Examiner Name	Unknown V. Nguyen
Sheet 1 of 2	Attorney Docket Number	X-719-ID-2D US	

U.S. PATENT DOCUMENTS						
Examiner Initials *	Cite No.¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code (if known)				
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FOREIGN PATENT DOCUMENTS						
Examiner Initials *	Cite No. *	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code *	Number - Kind Code * (if known)			
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W		JP	363079377 A	04-09-88	Kita	
W		JP	406163906 A	06-10-94	Natsume	

Examiner Signature	V. Nguyen	Date Considered	3/29/05
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Sheet	2	of	2	Attorney Docket Number	X-719-ID-2D US

OTHER - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No *	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T *
W		"Boron Diffusion And Penetration In Ultrathin Oxide With Poly-Si Gate"; Cao et al.; IEEE Electron Device Letters; Vol. 19; No. 8; August 1998; pp. 291-293	
W		"Flat-band Voltage Shifts In P-MOS Devices Caused By Carrier Activation In P+-Polycrystalline Silicon and Boron Penetration"; Aoyama et al.; 1997 IEEE; pp. 26.1.1 - 26.1.4	
W		"A PROM Element Based On Salicide Agglomeration Of Poly Fuses In A CMOS Logic Process"; Alavi et al.; 1997 IEEE; pp. 34.3.1 - 34.3.4	
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VIET Q. NGUYEN
 PRIMARY EXAMINER

Examiner Signature	V. Nguyen	Date Considered	3/20/05
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